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1781-0247P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Soo Jin CHUA et al.

Conf.: 5461

Appl. No.:

10/633,652

Group:

2812

Filed:

August 5, 2003

Examiner: MULPURI, S.

For:

FORMING INDIUM NITRIDE (INN) AND INDIUM

GALLIUM NITRIDE (INGAN) QUANTUM DOTS GROWN BY

METAL-ORGANIC-VAPOR-PHASE-EPITAXY (MOCVD)

## CHANGE OF ENTITY STATUS

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

June 21, 2004

Sir:

Applicant's representative had recently been informed that the above-identified application qualifies for large entity status as of February 5, 2003. Because the present application was filed under a small entity on August 3, 2003, Applicants herewith submit the difference in the fees in the amount of \$557.00 (i.e., a basic filing fee, one extra independent claim fee and multiple dependent claims fee).

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or credit any overpayment to Deposit Account No. 02-2448 for any additional fees required under 37 C.F.R. § 1.16 or under 37 C.F.R. § 1.17; particularly, extension of time fees.

06/28/2004 DALLEN 00000011 10633652

557.00 OP Adjustment date: 07/08/2004 AKELLEY 08/06/2003 HMARZI1 00000017 10633652 01 FC:2001 -375.

02 FC:2201 03 FC:2203 Adjustment date: 07/08/2004 AKELLEY 00000011 10633652 652 557.00 마본 06/28/2004 DALLEN

01 FC:1461<sub>DRN/mua</sub> 1781-0247P

01 FC:1461

Attachment(s)

Respectfully submitted,

BIRCH, STEWART, KOLASCH & BIRCH, LLP

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